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Article

# Exploring the Impact of the HOMO–LUMO Gap on Molecular Thermoelectric Properties: A Comparative Study of Conjugated Aromatic, Quinoidal, and Donor–Acceptor Core Systems

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coefficients of these compounds remain low. The alignment of the frontier orbitals relative to the Fermi energy was found to play a crucial role in determining the Seebeck coefficients, as exemplified by the BDP compounds. Theoretical calculations support these findings and suggest that anchor group selection could further enhance the thermoelectric behavior of these types of molecules.

# INTRODUCTION

Thermoelectric materials have the potential to revolutionize energy conversion by directly converting waste heat into useful electrical energy at room temperature without the need for any moving parts or environmentally harmful emissions.<sup>1</sup> They can be used in a variety of applications, ranging from power generation in automobiles and industrial processes via the Seebeck effect to cooling of electronics and other devices via the Peltier effect.<sup>2-4</sup> Current inorganic thermoelectric materials, such as bismuth telluride (Bi<sub>2</sub>Te<sub>3</sub>),<sup>5</sup> lead telluride (PbTe),<sup>6</sup> and silicon germanium (SiGe),<sup>7</sup> have been widely studied and utilized, but their applications are restricted due to toxicity and limited availability, as well as a generally low conversion efficiency at room temperature. Also, in most semiconductors, the increase in conductance is accompanied by a decrease of the Seebeck coefficient, which is not desirable and makes improving the thermoelectric efficiency a difficult task.<sup>8–14</sup>

urements revealed that despite their low H-L gaps, the Seebeck

These limitations have led to increased research on organic alternatives, which are more environmentally sustainable and potentially more efficient.<sup>15,16</sup> Improving the thermoelectric efficiency of such materials is achieved by simultaneously increasing the electrical conductance (G) and Seebeck

coefficient (S) while keeping the thermal conductance low.<sup>17,18</sup> Given that the Seebeck coefficient<sup>19</sup> relates to the gradient of the transmission curve (see eq 1), one of the most effective strategies to improve molecular thermopower is to employ quantum interference (QI), i.e., introducing a sharp resonance feature<sup>20-25</sup> within the highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) gap. However, this is often achieved using destructive QI, which results in reduced electrical conductance. An alternate approach that has yet to be directly examined is the impact of the HOMO-LUMO (H-L) gap and changes in the position of resonances.<sup>26-28</sup> In principle, the reduction of the H-L gap for a given molecule with a nonmid-gap Fermi energy  $(E_{\rm F})^{29-33}$  should result in an increased transmission gradient, i.e., Seebeck coefficient enhancement without any decrease in electrical conductance; see Figure 1.

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$$S = -\frac{\pi^2 k_{\rm B}^2}{3|e|} \frac{\partial \ln(T(E))}{\partial E} \bigg|_{E=E_{\rm E}}$$
(1)

where  $k_{\rm B}$  is the Boltzmann constant, *e* is the electron charge, and T(E) is the transmission probability as a function of energy, *E*.



**Figure 1.** Example of a transmission function that determines the probability that an electron of a given energy will tunnel through a molecular junction where  $\Delta E_i(H-L) > \Delta E_{ii}(H-L)$ . Increasing the transmission gradient around the Fermi energy by reducing the band gap can benefit the Seebeck coefficient.

Such a phenomenon has been used to explain the Seebeck coefficient increase for oligophenylene molecules as their length is extended.<sup>34,35</sup> However, the impacts were small in these examples and it was not until the work of Dell et al. using a donor–acceptor (D-A) system comprising thiophene D and oxidized oligothiophenes as A units that increasing the molecules' length, which reduced the H-L gap from 2.1 to 1.4 eV, was shown to result in a significant Seebeck coefficient change from +7.3 to  $-22.1 \ \mu V/K$ .<sup>36</sup> A similarly high Seebeck coefficient (ca. 15.5  $\ \mu V/K$ ) has also been observed for a 4,7-di(thiophen-2-yl)benzothiadiazole-based system.<sup>37</sup> However, both of the previous examples are D-A-based compounds; therefore, this question arises: is this a feature intrinsic to such systems or is it universal to all low-H-L-gap compounds?

To investigate this, we synthesized and measured the conductance and thermoelectric behavior of three different groups of compounds with an H-L gap <2.2 eV. The new molecules comprise an aromatic, a quinoidal (singlet diradical), and a D-A core system, based on isoindigo (IIG), benzodipyrrolidone (BDP), and bis(pyrrol-2-yl)squaraine (BPS), respectively. These structures were chosen due to their relatively simple structures and  $\pi$ -conjugated "linear" conductance paths, which should promote comparatively high electrical conductance and avoid complications from QI features. Herein, their conductance and thermoelectric properties were examined experimentally and theoretically at the single-molecule level in the tunneling regime.<sup>38</sup> For clarity, the IIG, BDP, and BPS derivatives are denoted as "1", "2", and "3", respectively, and their short and long variants are denoted as "a" and "b", respectively.

#### RESULTS AND DISCUSSION

**Synthesis.** Both the IGG-based (**1a** and **1b**) (Figure 2a) and BDP-based compounds (**2a** and **2b**) (Figure 2b) were synthesized using a dibromo-substituted building block (6,6'-dibromo-1,1'-dihexyl-[3,3'-biindolinylidene]-2,2'-dione<sup>39</sup> or 3,7-bis(4-bromophenyl)-1,5-dihexylpyrrolo[2,3]indole-2,6-dione, respectively) via Stille coupling with tributyl(4-(methylthio)phenyl)stannane or Sonogashira coupling with



Figure 2. Overview of the molecular structures of (a) 1a and 1b, (b) 2a and 2b, and (c) 3a and 3b. (d) Structure 3b (with Me representing an *n*-Hex chain for clarity) in a junction with gold electrodes, assumed to be the most likely geometry of the junction with both thiomethyl groups acting as anchors.

(4-ethynylphenyl)(methyl)sulfane to produce thiomethylanchored compounds. It is noteworthy that when Suzuki– Miyaura coupling was attempted with (4-(methylthio)phenyl)boronic acid and either of the dibromo-building blocks, there was no evidence of a reaction with the building blocks. The BPS compounds (**3a** and **3b**) (Figure 2c) were synthesized using an adaptation of So et al.'s approach,<sup>40</sup> whereby substituted 1-hexyl-pyrrole (1-hexyl-2-(4-(methylthio)phenyl)-1*H*-pyrrole or 1-hexyl-2-(4-((4-(methylthio)phenyl)ethynyl)phenyl)-1*H*-pyrrole) was heated with squaric acid to produce the respective BPS. All of the compounds were characterized using NMR spectroscopy, mass spectrometry, and elemental analysis, and compounds **1b** and **2b** were also characterized by single-crystal X-ray crystallography (see the Supporting Information (SI), Section A).

**Experimental Methods and Results.** All molecules were trapped in a goldlsingle moleculelgold junction, as illustrated in Figure 2d for 3b, for the measurement of electrical conductance and the Seebeck coefficient. These junctions were formed by using a homebuilt scanning tunneling microscope (STM) under ambient conditions. The molecules were deposited on a preannealed gold surface (Arrandee) from a ~1 mM solution in DCM. Then, a mechanically cut 0.25 mm diameter gold wire (Goodfellow) was used as the tip and indented to the surface. While retracting, the junction is reduced to the atomic level until the gold contact breaks, where statistically a single molecule is contacted between the

tip and the sample. These were connected electrically to apply a bias voltage and measure the current, hence acting as electrodes. The procedure was performed thousands of times at a constant bias voltage of 100 mV to measure the current when the junction breaks to obtain the current vs distance traces (insets in Figure 3a,b). When a molecule is contacted,



Figure 3. (a,b) Conductance histograms for short "a" and long "b" counterparts of compounds 1, 2, and 3 and (inset) examples of individual traces showing a molecular plateau around the mean value of the conductance distribution for each compound.

there is a plateau between the single-atom plateau at a conductance of  $G_0 = 7.75 \times 10^{-5}$  S and the noise level of the open circuit. These traces were used to build the conductance histograms shown in Figure 3a,b, where the counts create a distribution around the most probable conductance value.

The Seebeck coefficient is determined by performing current vs voltage ramps of  $\pm 10$  mV when a plateau is detected.<sup>41</sup> A 1 k $\Omega$  resistance implemented in the tip holder is used to heat the tip, creating a temperature difference between the electrodes (tip-sample). The thermoelectric effect causes a displacement of the *I*-*V* curves. The offsets in the current and voltage of the system are calibrated after every junction by measuring the *I*-*V* curves in the open circuit and switching the electronic path to a resistance in parallel to the STM. The remaining offset corresponds to the thermovoltage, while the slope of the *I*-*V* curves is the conductance, thus allowing the measurement of

both parameters simultaneously. The Seebeck coefficient is obtained as the slope in the fitting of the linear regression of the temperature difference dependence of the thermovoltage, as shown in Figure 4.

In Figure 3a,b, the conductance histograms of each compound display a main conductance distribution around the most probable conductance value. The relatively narrow breadth of the conductance histogram peaks is indicative of a rigid molecule anchored with thiomethyl groups. The relatively small plateaus compared to the length of the compounds (see the SI, Section B) indicate that the molecule is not fully spanning the junction, possibly remaining in a tilted position before detachment.<sup>42</sup> This makes the quantitative determination of the breakoff distance difficult to achieve. However, a comparison of conductance vs distance histograms (Figure S28) shows that qualitatively the longer molecules (1b, 2b, and 3b) have a greater junction elongation than the shorter analogues (1a, 2a, and 3a), consistent with an increase in molecular length in the "b" series.

As often observed in single-molecule measurements,<sup>43</sup> the short compounds (1a, 2a, and 3a) demonstrated higher conductance values than their longer analogues (1b, 2b, and 3b); i.e., 1a and 1b have conductance values of -4.4 and  $-5.0 \log(G/G_0)$ , and 2a and 2b, -5.2 and  $-5.6 \log(G/G_0)$ , respectively. Compounds 3a and 3b showed the greatest decrease in conductance upon elongation of the molecular backbone, with values of -3.8 to  $-5.5 \log(G/G_0)$  respectively, which can be explained by this pair having the largest increase in conjugation length. Based on oligo(phenylene ethynylene)  $\beta$ -values of 3.4 nm<sup>-1,44</sup> it is possible to empirically compare the relative conductance of the long and short molecules to show that despite the length of the molecules, the conductance attenuation is consistent with a tunneling regime (see the SI, Section B).

The Seebeck coefficients in each case are negative (Figure 4), indicating LUMO-dominated transport, which is supported by our calculations below (Figure 5). Previous studies with SMe anchors provide precedents for either HOMO- or LUMO-dominated transport.<sup>36,45–48</sup> Compounds 1a and 1b



Figure 4. Most probable thermovoltage values with the dispersion as error bars and linear regressions performed to all data points of the temperature difference dependence of the thermovoltage measurements of compounds (a) 1a, (b) 1b, (c) 2a, (d) 2b, (e) 3a, and (f) 3b in the dark and (g) 3a and (h) 3b in light, in the selected traces that show a molecular response measured for several temperature differences. The measurements in light are without the high Seebeck value data points.



Figure 5. Transmission, conductance, and Seebeck coefficients of compounds 1a, 1b, 2a, 2b, 3a, and 3b. (a) DFT electron transmission probabilities of compounds 1a, 1b, 2a, 2b, 3a, and 3b. (b) Measured and theoretical conductances at a Fermi energy of -0.36 eV. (c) Theoretical Seebeck coefficients. (d) Measured and theoretical Seebeck coefficients at a Fermi energy of -0.36 eV.

had similarly low values of -0.9 and  $-0.5 \mu V/K$ , respectively (Figure 4a,b), indicating that the position of  $E_{\rm F}$  is close to the center of the H-L gap. Compounds 2a and 2b (Figure 4c,d) had higher values, -4.1 and  $-4.8 \mu V/K$ , respectively, even though these compounds had a higher H-L gap (Table S2), suggesting a higher transmission gradient around the Fermi energy. Compounds 3a and 3b (Figure 4e,f) have Seebeck coefficients of -2.7 and  $-0.4 \mu V/K$ , respectively, showing the atypical trend of the Seebeck coefficient reducing as the conjugation length increases.<sup>19</sup>

Theoretical Method and Results. First principles calculations were performed to further understand the thermoelectric properties of compounds 1a, 1b, 2a, 2b, 3a, and 3b. Initially, the ground-state geometry of the molecular structures was obtained using a self-consistent scheme implemented in the  ${\rm SIESTA}^{49}$  density functional theory code. Once the relaxed structure was determined, it was positioned in a junction between two gold leads to obtain the ground-state structures after geometry optimization. The DFT mean-field Hamiltonians of these structures were then combined with GOLLUM<sup>50</sup> using the nonequilibrium Green's function method to calculate the electron transmission,<sup>51</sup> with further details provided in Section D of the SI. The eigenvalues show that both BDP compounds, 2a and 2b, have the smallest H-L gap (1.09 and 0.99 eV, respectively), with both their LUMO energies closest to the  $E_{\rm F}$  compared to those of the other compounds, with an about 0.3 eV difference. All compounds show clear continuum-state orbitals with the LUMO orbitals localized around the core of the backbone of the molecule (Figure S37a-c).

The electron transmission was calculated for IIG (1a and 1b), BDP (2a and 2b), and BPS (3a and 3b) compounds. The transmission curves (see Figure 5a) for each of the compounds are featureless within the H-L gap; i.e., there is no suggestion of DQI features. Compounds 1b (1.46 eV) and 3b (1.28 eV) clearly show smaller H-L gaps compared to those of their shorter analogues 1a (1.65 eV) and 3a (1.57 eV). However, 2a

(1.11 eV) and **2b** (1.09 eV) have a very similar H-L gap size consistent with measured H-L gap data (see Table S2). Given how significantly the alignment of  $E_{\rm F}$  can determine the conductive behavior of a system, we started by comparing the measured conductance and Seebeck coefficients. Due to the negative sign of the Seebeck coefficient, the conductance is LUMO dominated and the comparison of the calculated transmission curve and measured values determined that an  $E_{\rm F}$  = -0.36 eV gives the closest match; i.e., this predicts conductances of -4.3, -4.5, -4.0, -4.6, -4.4, and -5.2 log( $G/G_0$ ) for 1a, 1b, 2a, 2b, 3a, and 3b, respectively, reproducing the attenuation attributed to molecular length (Figure 5b). The full conductance plots are shown in Figure S38.

The Seebeck coefficients of these compounds were derived from the DFT transmission using the method explained in the SI, Section D (Figure 5c), giving values of -10, -2.7, -24, -26, -12.5, and  $-0.6 \mu$ V/K for 1a, 1b, 2a, 2b, 3a, and 3b, respectively (Figure 5d). Compounds 1a and 3a have higher Seebeck coefficients compared to their longer analogues 1b and 3b, due to the pinning of the LUMO resonance (as a result of the type of anchor), meaning that the gradient of the transmission around the Fermi energy is less for 1b and 3b. While compounds 2a and 2b have very similar H-L gap sizes, the higher Seebeck coefficient for 2b is due to a narrower LUMO transport resonance, leading to a higher slope at the Fermi energy and consequently a higher S.

These results highlight that rather than it being exclusively the result of the H-L gap or a particular class of compounds, it is the position of the frontier orbitals relative to  $E_{\rm F}$  that has the dominant role in determining the Seebeck coefficients of the molecular wires. This is particularly exemplified by the BDP compounds (2a and 2b). We expanded on this observation by using theoretical models to examine how varying the anchor group changes the Seebeck coefficients by replacing the thioanisole groups of 2a, 2b, 3a, and 3b with either pyridyl (2a-Py, 2b-Py, 3a-Py, and 3b-Py) or benzonitrile (2a-CN and 2b-CN) anchors (see Figure S39). Using this approach, it has been shown that for 3a and 3b, a shift of the LUMO relative to  $E_{\rm F}$  by approximately 0.1 eV (Py) and 0.08 eV (CN), although small, would give a theoretical Seebeck coefficient increase due to an increased transmission slope (Figure S40). Furthermore, to understand the effect of molecular conformation on the thermoelectric properties, we studied these properties, in bent junctions formed by 3a and 3b. We found that while, in agreement with previous reports,<sup>52–55</sup> the values obtained are sensitive to the conformations, the trend observed is not and is in agreement with the trend observed experimentally as shown in Figure S41.

It is worth noting that the thermoelectric measurements of the BPS compounds (**3a** and **3b**) proved to be fickler than those of the other molecules due to their light sensitivity when on a gold surface (see the SI, Section B). All compounds were characterized under ambient light conditions. In the case of the two compounds (**3a** and **3b**), their most probable Seebeck values were  $-0.7 \ \mu\text{V/K}$  for **3a** and  $+2.6 \ \mu\text{V/K}$  for **3b** (Figure 4e,f). It was observed that these values drifted over time, becoming more positive. Repeating the measurements without light gave the original, stable values ( $-2.7 \ \mu\text{V/K}$  for **3a** and  $-0.4 \ \mu\text{V/K}$  for **3b**), confirming the light's effect on the Seebeck coefficient (see the SI for more details). This suggests that the molecules degraded in the presence of light, which was further confirmed by X-ray photoelectron spectroscopic (XPS) data in the SI. However, this degradation did not have a significant effect on their electrical conductance.

To understand this further, we investigated theoretically the possible scenarios (as shown in the SI, Section D). We found that changes to the molecules' structure, or the formation of bimolecules bonded together either through  $\pi$ – $\pi$  stacking or through a covalent bond, lead to changes in the QI pattern through molecules **3a** and **3b**, which in turn influence the slope of transmission curves (and consequently *S*) more significantly than their amplitude (and consequently *G*). This is also in line with the additional features we observed experimentally under light, depicted in Figure S31e,f, where we found two distinct values for both compounds: around -7 and -23  $\mu$ V/K for **3a** and around -75 and -117  $\mu$ V/K for **3b** as shown in Figure 4g,h (see the SI, Section B, for more details), each with a yield lower than 5%.

## CONCLUSIONS

A series of aromatic (IIG), quinoidal (BDP), and D-A (BPS) small-H-L-gap molecules end-capped with thioanisole groups was synthesized to examine the impact of the H-L gap on the Seebeck coefficients in goldlsingle moleculelgold junctions. Due to their combination of relatively simple structures and linear  $\pi$ -conjugated conductance paths, comparatively high electrical conductances were established and impacts of destructive QI features were avoided. Through the measurement of Seebeck coefficients, it was established that the conductance of all of the compounds was LUMO dominated. However, despite the relatively low H-L gap of the compounds, the magnitude of the Seebeck coefficients remained low, which can be explained by the relative positions of  $E_{\rm F}$  to the frontier orbitals. Therefore, from this study, it can be concluded that to fully exploit enhancement in thermoelectric behavior resulting from H-L gap reduction, it is necessary to make a judicious choice of molecular components to better match the orbitals' alignment with  $E_{\rm F}$ . As a first step in future studies, different anchor groups could be investigated.

# METHODOLOGY

**Synthesis.** The SI contains the synthesis procedures and characterizations.

**Measurement.** Conductance and Seebeck coefficient measurements were carried out using a homebuilt STM at room temperature and under ambient conditions, and a moderate temperature range was chosen as our heating method is limited by the voltage that can be applied to the resistance in the tip holder (see the SI for details).

**Theory.** The optimized geometries with ground-state Hamiltonian and overlap matrix elements for gas-phase molecules and molecules between electrodes were obtained using DFT. These results were then combined with the Green's function method to calculate the phase-coherent, elastic-scattering properties of the system, consisting of two gold electrodes and the molecule as the scattering region. From the calculated transmission functions, the electrical conductance and the Seebeck coefficient were calculated. See the SI for details of computational methods.

# ASSOCIATED CONTENT

## **Data Availability Statement**

The experimental data underlying this study are openly available in ZENODO at DOI: 10.5281/zenodo.10549417.

#### **Supporting Information**

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/acsomega.3c09760.

Experimental procedures, synthesis, NMR spectra, crystallographic and photophysical data, compound stability, conductance and Seebeck measurements, XPS data and theoretical data, crystallographic data for compounds 1a and 1b (CSD 2301298 and 2301299, respectively) (PDF)

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# Notes

The authors declare no competing financial interest.

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#### REFERENCES

(1) Gemma, A.; Gotsmann, B. A Roadmap for Molecular thermoelectricity. *Nature Nanotechnol.* **2021**, 1299–1301.

(2) Rincón-García, L.; Evangeli, C.; Rubio-Bollinger, G.; Agraït, N. thermopower Measurements in Molecular Junctions. *Chem. Soc. Rev.,* Royal Society of Chemistry, 7, 2016; pp 4285–4306.

(3) Russ, B.; Glaudell, A.; Urban, J. J.; Chabinyc, M. L.; Segalman, R. A. Organic Thermoelectric Materials for Energy Harvesting and Temperature Control. *Nat. Rev. Mater.* **2016**, *1* (10), 16050.

(4) Wang, K.; Meyhofer, E.; Reddy, P. Thermal and Thermoelectric Properties of Molecular Junctions. *Adv. Funct Mater.* **2020**, *30* (8), 1904534.

(5) Witting, I. T.; Chasapis, T. C.; Ricci, F.; Peters, M.; Heinz, N. A.; Hautier, G.; Snyder, G. J. The Thermoelectric Properties of Bismuth telluride. *Adv. Electron. Mater.*, Blackwell Publishing Ltd *5*, 2019, 1800904.

(6) Sharma, P. K.; Senguttuvan, T. D.; Sharma, V. K.; Chaudhary, S. Revisiting the Thermoelectric Properties of Lead telluride. *Mater. Today Energy* **2021**, *21*, No. 100713.

(7) Samarelli, A.; Ferre Llin, L.; Cecchi, S.; Frigerio, J.; Chrastina, D.; Isella, G.; Müller Gubler, E.; Etzelstorfer, T.; Stangl, J.; Zhang, Y.; Weaver, J. M. R.; Dobson, P. S.; Paul, D. J. Prospects for SiGe Thermoelectric Generators. *Solid-State Electron.* **2014**, *98*, 70–74.

(8) Park, S.; Kang, S.; Yoon, H. J. Power Factor of One Molecule Thick Films and Length Dependence. *ACS Cent Sci.* 2019, 5 (12), 1975–1982.

(9) Park, S.; Jang, J.; Tanaka, Y.; Yoon, H. J. High Seebeck Coefficient Achieved by Multinuclear Organometallic Molecular Junctions. *Nano Lett.* **2022**, *22* (23), 9693–9699.

(10) Kang, H.; Jang, J.; Kong, G. D.; Jung, S.; Ohto, T.; Yoon, H. J. Deposition Condition Impacts Charge Tunneling and Thermoelectric Properties of N-Heterocyclic Carbene Monolayers. *J. Mater. Chem. A Mater.* **2023**, *11* (30), 16233–16242.

(11) Salthouse, R. J.; Hurtado-Gallego, J.; Grace, I. M.; Davidson, R.; Alshammari, O.; Agraït, N.; Lambert, C. J.; Bryce, M. R. Electronic Conductance and thermopower of Cross-Conjugated and Skipped-Conjugated Molecules in Single-Molecule Junctions. *J. Phys. Chem. C* **2023**, *127* (28), 13751–13758.

(12) Naher, M.; Milan, D. C.; Al-Owaedi, O. A.; Planje, I. J.; Bock, S.; Hurtado-Gallego, J.; Bastante, P.; Abd Dawood, Z. M.; Rincón-

García, L.; Rubio-Bollinger, G.; Higgins, S. J.; Agraït, N.; Lambert, C. J.; Nichols, R. J.; Low, P. J. Molecular Structure-(Thermo)Electric Property Relationships in Single-Molecule Junctions and Comparisons with Single- And Multiple-Parameter Models. *J. Am. Chem. Soc.* **2021**, *143* (10), 3817–3829.

(13) Hurtado-Gallego, J.; Sangtarash, S.; Davidson, R.; Rincón-García, L.; Daaoub, A.; Rubio-Bollinger, G.; Lambert, C. J.; Oganesyan, V. S.; Bryce, M. R.; Agraït, N.; Sadeghi, H. Thermoelectric Enhancement in Single Organic Radical Molecules. *Nano Lett.* **2022**, 22 (3), 948–953.

(14) Fujii, S.; Montes, E.; Cho, H.; Yue, Y.; Koike, M.; Nishino, T.; Vázquez, H.; Kiguchi, M. Mechanically Tuned thermopower of Single-Molecule Junctions. *Adv. Electron. Mater.* **2022**, 8 (12), 2200700.

(15) Lee, S.; Kim, S.; Pathak, A.; Tripathi, A.; Qiao, T.; Lee, Y.; Lee, H.; Woo, H. Y. Recent Progress in Organic Thermoelectric Materials and Devices. *Macromol. Res.* **2020**, *28* (6), 531–552.

(16) Zeng, Y. J.; Wu, D.; Cao, X. H.; Zhou, W. X.; Tang, L. M.; Chen, K. Q. Nanoscale Organic Thermoelectric Materials: Measurement, Theoretical Models, and Optimization Strategies. *Adv. Funct Mater.* **2020**, *30* (8), 1903873.

(17) Sangtarash, S.; Sadeghi, H. Radical Enhancement of Molecular Thermoelectric Efficiency. *Nanoscale Adv.* **2020**, 2 (3), 1031–1035.

(18) Chelli, Y.; Sandhu, S.; Daaoub, A. H. S.; Sangtarash, S.; Sadeghi, H. Controlling Spin Interference in Single Radical Molecules. *Nano Lett.* **2023**, *23* (9), 3748–3753.

(19) Park, S.; Kang, H.; Yoon, H. J. Structure-thermopower Relationships in Molecular Thermoelectrics. J. Mater. Chem. A Mater. 2019, 7 (24), 14419–14446.

(20) Miao, R.; Xu, H.; Skripnik, M.; Cui, L.; Wang, K.; Pedersen, K. G. L.; Leijnse, M.; Pauly, F.; Wärnmark, K.; Meyhofer, E.; Reddy, P.; Linke, H. Influence of Quantum Interference on the Thermoelectric Properties of Molecular Junctions. *Nano Lett.* **2018**, *18* (9), 5666–5672.

(21) Cao, X. H.; Wu, D.; Feng, Y. X.; Zhou, W. X.; Tang, L. M.; Chen, K. Q. Effect of Electrophilic Substitution and Destructive Quantum Interference on the Thermoelectric Performance in Molecular Devices. J. Phys.: Condens. Matter **2019**, 31 (34), 345303.

(22) Cao, J.; Tan, X. Y.; Jia, N.; Lan, D.; Solco, S. F. D.; Chen, K.; Chien, S. W.; Liu, H.; Tan, C. K. I.; Zhu, Q.; Xu, J.; Yan, Q.; Suwardi, A. Improved: ZT in Nb5Ge3-GeTe Thermoelectric Nanocomposite. *Nanoscale* **2022**, *14* (2), 410–418.

(23) Sadeghi, H. Quantum and Phonon Interference-Enhanced Molecular-Scale thermoelectricity. J. Phys. Chem. C 2019, 123 (20), 12556–12562.

(24) Grace, I. M.; Olsen, G.; Hurtado-Gallego, J.; Rincón-Garciá, L.; Rubio-Bollinger, G.; Bryce, M. R.; Agraït, N.; Lambert, C. J. Connectivity Dependent thermopower of Bridged Biphenyl Molecules in Single-Molecule Junctions. *Nanoscale* **2020**, *12* (27), 14682– 14688.

(25) Xiaohui, X.; et al. Scaling of Quantum Interference from Single Molecules to Molecular Cages and Their Monolayers. *Proc. Natl. Acad. Sci. U.S.A.* **2022**, *119* (46), No. e2211786119.

(26) Park, S.; Jang, J.; Yoon, H. J. Validating the Mott Formula with Self-Assembled Monolayer (SAM)-Based Large-Area Junctions: Effect of Length, Backbone, Spacer, Substituent, and Electrode on the thermopower of SAMs. *J. Phys. Chem. C* **2021**, *125* (36), 20035–20047.

(27) Tan, A.; Balachandran, J.; Sadat, S.; Gavini, V.; Dunietz, B. D.; Jang, S. Y.; Reddy, P. Effect of Length and Contact Chemistry on the Electronic Structure and Thermoelectric Properties of Molecular Junctions. J. Am. Chem. Soc. **2011**, 133 (23), 8838–8841.

(28) Quek, S. Y.; Choi, H. J.; Louie, S. G.; Neaton, J. B. thermopower of Amine-Gold-Linked Aromatic Molecular Junctions from First Principles. *ACS Nano* **2011**, *5* (1), 551–557.

(29) Backhaus-Ricoult, M.; Rustad, J.; Moore, L.; Smith, C.; Brown, J. Semiconducting Large Bandgap Oxides as Potential Thermoelectric Materials for High-Temperature Power Generation? *Appl. Phys. A Mater. Sci. Process* **2014**, *116* (2), 433–470.

(30) Witting, I. T.; Chasapis, T. C.; Ricci, F.; Peters, M.; Heinz, N. A.; Hautier, G.; Snyder, G. J. The Thermoelectric Properties of Bismuth telluride. *Adv. Electron Mater.* **2019**, 5 (6), 1800904.

(31) Jung, I. H.; Hong, C. T.; Lee, U. H.; Kang, Y. H.; Jang, K. S.; Cho, S. Y. High Thermoelectric Power Factor of a Diketopyrrolopyrrole-Based Low Bandgap Polymer via Finely Tuned Doping Engineering. *Sci. Rep* **201**7, *7*, 44704.

(32) Wei, T. R.; Wang, H.; Gibbs, Z. M.; Wu, C. F.; Snyder, G. J.; Li, J. F. Thermoelectric Properties of Sn-Doped p-Type Cu3SbSe 4: A Compound with Large Effective Mass and Small Band Gap. J. Mater. Chem. A Mater. 2014, 2 (33), 13527–13533.

(33) Famili, M.; Grace, I. M.; Al-Galiby, Q.; Sadeghi, H.; Lambert, C. J. Toward High Thermoelectric Performance of Thiophene and Ethylenedioxythiophene (EDOT) Molecular Wires. *Adv. Funct Mater.* **2018**, *28* (15), 1703135.

(34) Malen, J. A.; Doak, P.; Baheti, K.; Don Tilley, T.; Segalman, R. A.; Majumdar, A. Identifying the Length Dependence of Orbital Alignment and Contact Coupling in Molecular Heterojunctions. *Nano Lett.* **2009**, *9* (3), 1164–1169.

(35) Widawsky, J. R.; Chen, W.; Vázquez, H.; Kim, T.; Breslow, R.; Hybertsen, M. S.; Venkataraman, L. Length-Dependent thermopower of Highly Conducting Au-C Bonded Single Molecule Junctions. *Nano Lett.* **2013**, *13* (6), 2889–2894.

(36) Dell, E. J.; Capozzi, B.; Xia, J.; Venkataraman, L.; Campos, L. M. Molecular Length Dictates the Nature of Charge Carriers in Single-Molecule Junctions of Oxidized Oligothiophenes. *Nat. Chem.* **2015**, 7 (3), 209–214.

(37) Guo, S.; Zhou, G.; Tao, N. Single Molecule Conductance, thermopower, and Transition Voltage. *Nano Lett.* **2013**, *13* (9), 4326–4332.

(38) Lu, Q.; Liu, K.; Zhang, H.; Du, Z.; Wang, X.; Wang, F. From Tunneling to Hopping: A Comprehensive Investigation of Charge Transport Mechanism in Molecular Junctions Based on Oligo(p-Phenylene Ethynylene)s. *ACS Nano* **2009**, *3* (12), 3861–3868.

(39) Estrada, L. A.; Liu, D. Y.; Salazar, D. H.; Dyer, A. L.; Reynolds, J. R. Poly[Bis-EDOT-Isoindigo]: An Electroactive Polymer Applied to Electrochemical Supercapacitors. *Macromolecules* **2012**, *45* (20), 8211–8220.

(40) So, S.; Choi, H.; Kim, C.; Cho, N.; Ko, H. M.; Lee, J. K.; Ko, J. Novel Symmetric squaraine Chromophore Containing Triphenylamine for Solution Processed Small Molecule Bulk Heterojunction Solar Cells. *Sol. Energy Mater. Sol. Cells* **2011**, 95 (12), 3433–3441.

(41) Evangeli, C.; Gillemot, K.; Leary, E.; González, M. T.; Rubio-Bollinger, G.; Lambert, C. J.; Agraït, N. Engineering the thermopower of C60 Molecular Junctions. *Nano Lett.* **2013**, *13* (5), 2141–2145.

(42) Leary, E.; González, M. T.; van der Pol, C.; Bryce, M. R.; Filippone, S.; Martín, N.; Rubio-Bollinger, G.; Agraït, N. Unambiguous One -Molecule Conductance Measurements under Ambient Conditions. *Nano Lett.* **2011**, *11* (6), 2236–2241.

(43) Su, T. A.; Neupane, M.; Steigerwald, M. L.; Venkataraman, L.; Nuckolls, C. Chemical Principles of Single-Molecule Electronics. *Nat. Rev. Mater.* **2016**, *1*, 16002.

(44) Kaliginedi, V.; Moreno-García, P.; Valkenier, H.; Hong, W.; García-Suárez, V. M.; Buiter, P.; Otten, J. L. H.; Hummelen, J. C.; Lambert, C. J.; Wandlowski, T. Correlations between Molecular Structure and Single-Junction Conductance: A Case Study with Oligo(Phenylene-Ethynylene)-Type Wires. J. Am. Chem. Soc. 2012, 134 (11), 5262–5275.

(45) Hurtado-Gallego, J.; Davidson, R.; Grace, I. M.; Rincón-García, L.; Batsanov, A. S.; Bryce, M. R.; Lambert, C. J.; Agraït, N. Quantum Interference Dependence on Molecular Configurations for Cross-Conjugated Systems in Single-Molecule Junctions. *Mol. Syst. Des. Eng.* **2022**, 7 (10), 1287–1293.

(46) Reznikova, K.; Hsu, C.; Schosser, W. M.; Gallego, A.; Beltako, K.; Pauly, F.; Van Der Zant, H. S. J.; Mayor, M. Substitution Pattern Controlled Quantum Interference in [2.2]Paracyclophane-Based Single-Molecule Junctions. *J. Am. Chem. Soc.* **2021**, *143* (34), 13944–13951.

(47) Yzambart, G.; Rincón-García, L.; Al-Jobory, A. A.; Ismael, A. K.; Rubio-Bollinger, G.; Lambert, C. J.; Agraït, N.; Bryce, M. R. Thermoelectric Properties of 2,7-Dipyridylfluorene Derivatives in Single-Molecule Junctions. *J. Phys. Chem.* C **2018**, *122* (48), 27198–27204.

(48) Ismael, A.; Wang, X.; Bennett, T. L. R.; Wilkinson, L. A.; Robinson, B. J.; Long, N. J.; Cohen, L. F.; Lambert, C. J. Tuning the Thermoelectrical Properties of Anthracene-Based Self-Assembled Monolayers. *Chem. Sci.* **2020**, *11* (26), 6836–6841.

(49) Soler, J. M.; Artacho, E.; Gale, J. D.; García, A.; Junquera, J.; Ordejón, P.; Sánchez-Portal, D. The Siesta Method for Ab Initio Order-N Materials Simulation. *J. Phys.: Condens. Matter* **2002**, *14*, 2745.

(50) Ferrer, J.; Lambert, C. J.; Garcia-Suarez, V. M.; Manrique, D. Zs.; Visontai, D.; Oroszlany, L.; Rodriguez-Ferradas, R.; Grace, I.; Bailey, S. W. D.; Gillemot, K.; Sadeghi, H.; Algharagholy, L. A. GOLLUM: A next-Generation Simulation Tool for Electron, Thermal and Spin Transport. *New J. Phys.* **2014**, *16*, No. 093029.

(51) Sadeghi, H. Theory of Electron, Phonon and Spin Transport in Nanoscale Quantum Devices. *Nanotechnology* **2018**, *29* (37), 373001.

(52) Daaoub, A.; Ornago, L.; Vogel, D.; Bastante, P.; Sangtarash, S.; Parmeggiani, M.; Kamer, J.; Agraït, N.; Mayor, M.; Van Der Zant, H.; Sadeghi, H. Engineering Transport Orbitals in Single-Molecule Junctions. J. Phys. Chem. Lett. **2022**, 13 (39), 9156–9164.

(53) Wu, C.; Bates, D.; Sangtarash, S.; Ferri, N.; Thomas, A.; Higgins, S. J.; Robertson, C. M.; Nichols, R. J.; Sadeghi, H.; Vezzoli, A. Folding a Single-Molecule Junction. *Nano Lett.* **2020**, *20* (11), 7980–7986.

(54) Alsaqer, M.; Daaoub, A. H. S.; Sangtarash, S.; Sadeghi, H. Large Mechanosensitive Thermoelectric Enhancement in Metallo-Organic Magnetic Molecules. *Nano Lett.* **2023**, *23*, 10719.

(55) Daaoub, A.; Morris, J. M. F.; Béland, V. A.; Demay-Drouhard, P.; Hussein, A.; Higgins, S. J.; Sadeghi, H.; Nichols, R. J.; Vezzoli, A.; Baumgartner, T.; Sangtarash, S. Not So Innocent After All: Interfacial Chemistry Determines Charge-Transport Efficiency in Single-Molecule Junctions. *Angew. Chem. - Int. Ed.* **2023**, *62* (24), No. e202302150.